









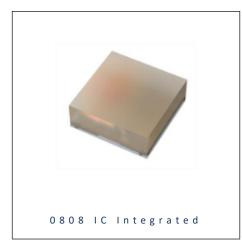




- ► CHIP SMD with IC
- ▶ 0808 (2020) IC 0.75t
- ► Red/Green/Blue

N0M48S82IC





FEATURES:



Forward Current: 5mA

Forward Voltage (typ.): +3.8~+5.5V

Luminous Intensity (typ.): 300mcd mixed white

0808 IC-Integrated Compliant

Colour: Red/Green/Blue

Wavelength: 622/527/467nm

Viewing angle: 120°

Materials:

Resin: Silicone (Water Diffused)

L/F Finish: Ag Plated

Operating Temperature: -40~+85°C

Storage Temperature: -40~+105°C

IC Feature: Serial data transmission signal by single wire.

Pixel: One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours. Internal clock frequency operates at 800kHz.

Soldering methods: IR Reflow soldering

Preconditioning: acc. to JEDEC Level 3

Packing: 8mm tape with Max.4000pcs/reel, ø180mm (7")

APPLICATIONS:

- Telecommunication
- Indicator
- Home Appliance
- **Decoration Lighting**



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	l _F	5	mA
IC Power Supply Voltage	V _{DD}	+3.8~+5.5	V
IC Input Voltage	Vı	-0.4~V _{DD} +0.4	V
Operating Temperature	T _{OPR}	-40~+85	°C
Storage Temperature	T _{STG}	-40~+105	°C
Soldering Temperature	T _{SD}	260	°C

Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Symbol	Values			Unit	Test
		Зуппоот	Min.	Тур.	Max.	Offic	Condition
Forward Voltage		V _F	3.8	5	5.5	V	I _F =5mA
	R		40	75	125	mcd	I⊧=5mA
Luminaus Intensitu	G	,	135	230	390		
Luminous Intensity	В	lv	15	35	75		
	W		120	300	600		
	R	λ_{D}	615		630	nm	I _F =5mA
Dominant Wavelength	G		520		535		
	В		460		475		
Colour Coordinate	Х			0.2620			IEmA
Colour Coordinate	Υ			0.3130			I _F =5mA
Viewing Angle		2θ _{1/2}		120		deg	I _F =5mA



Electrical & Optical Characteristics (Ta=25°C)

Darameter	Symbol	Values			Unit	Test
Parameter	Зуппоп	Min.	Тур.	Max.	Onit	Condition
Static Current	I _{DD}		0.3		mA	V _{DD} =4.5V I _{out} =OFF
Input Voltage Level	V _{IH}	0.7 V _{DD}			V	D _{IN} , SET
Input Voltage Level	VIL			0.3 V _{DD}	V	D _{IN} , SET

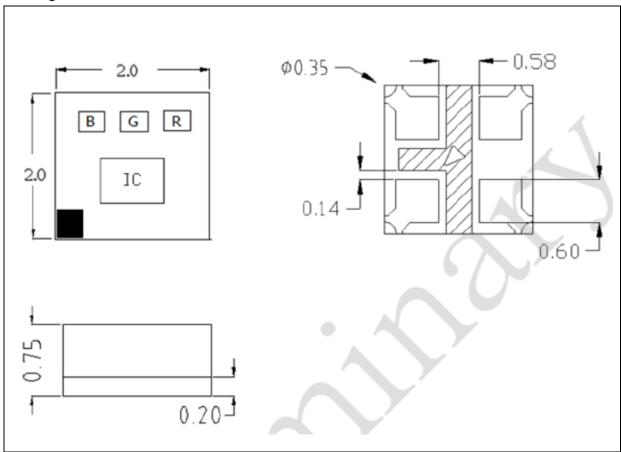
Switching Characteristics (Ta=25°C)

Parameter	Symbol	Values			Unit	Test	
Parameter	Зуппоп	Min.	Тур.	Max.	UIIIL	Condition	
Rate of Data Signal	F _{DIN}		0.8		MHz		
Tuonafau Timo	T _{PLH}			80	ns	D \ \ D	
Transfer Time	T _{PHL}			80	ns	Din → Dout	
Conversion Time of L. D./C./D.	Tr			50	ns	I _{оит} R/G/B=5mA	
Conversion Time of Iout R/G/B	T _f			100	ns	RL=400Ω CL=15pF	



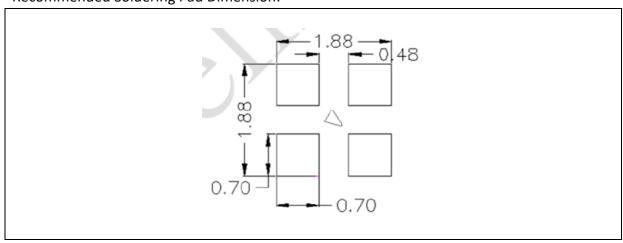
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.2mm, unless otherwise noted.

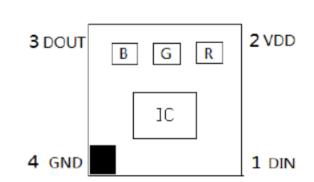
Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



PIN CONFIGURATION:



No.	Symbol	Function Description
1	DIN	Control Data Signal Input
2	VDD	Power Supply LED
3	DOUT	Control Data Signal Output
4	GND	Ground



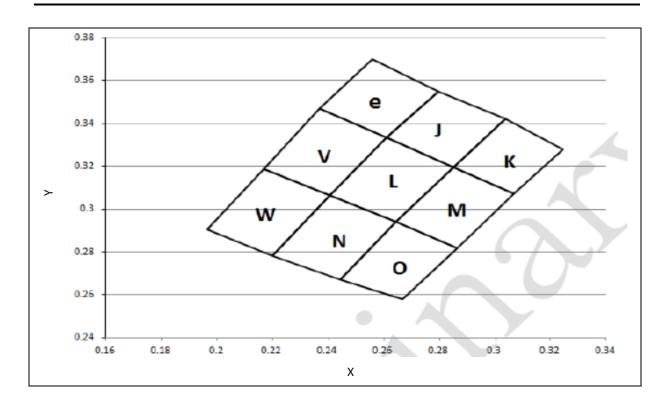
BINNING GROUPS:

Luminous Intensity Classifications (White) ($I_F = 5mA$, $V_{DD}=5V$):

Code	Min.	Max.	Unit
8	160	210	
9	210	270	
10	270	350	mcd
11	350	460	
12	460	600	



CIE CHROMATICITY DIAGRAM:



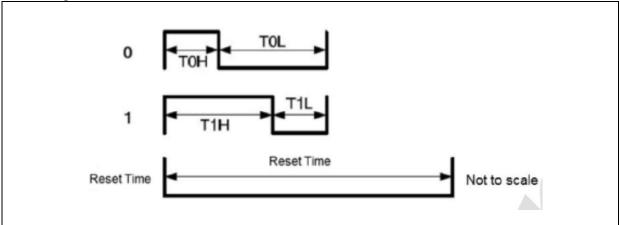
Chromaticity Coordinates Classifications (I_F = 5mA):

	:	1	2	2	3	3	4	1
	Х	Y	Х	Y	Х	Υ	Х	Υ
е	0.2369	0.3468	0.2609	0.3332	0.2797	0.3550	0.2559	0.3698
J	0.2609	0.3332	0.2797	0.3550	0.3036	0.3420	0.2849	0.3196
К	0.2851	0.3196	0.3036	0.3420	0.3243	0.3280	0.3068	0.3072
V	0.2169	0.3188	0.2369	0.3468	0.3609	0.3332	0.2406	0.3064
L	0.2406	0.3064	0.2609	0.3332	0.2849	0.3196	0.2643	0.2940
М	0.2643	0.2940	0.2849	0.3196	0.3068	0.3072	0.2865	0.2819
W	0.1963	0.2907	0.2169	0.3188	0.2406	0.3064	0.2200	0.2783
N	0.2200	0.2783	0.2406	0.3064	0.2643	0.2940	0.2444	0.2672
0	0.2444	0.2672	0.2643	0.2940	0.2865	0.2819	0.2667	0.2578



Function Description - Data Transfer Time (TH+TL=1.2µs±300ns):

1. Timing Wave Form:



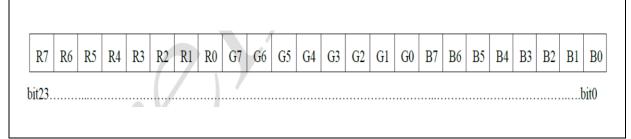
2. High Speed Mode:

Item	Description	Typical	Allowance
Тон	0 code, high voltage time	300ns	±150ns
ToL	0 code, low voltage time	900ns	±150ns
T _{1H}	1 code, high voltage time	900ns	±150ns
T ₁ L	1 code, low voltage time	300ns	±150ns
RES	reset time	>200us	-

Note:

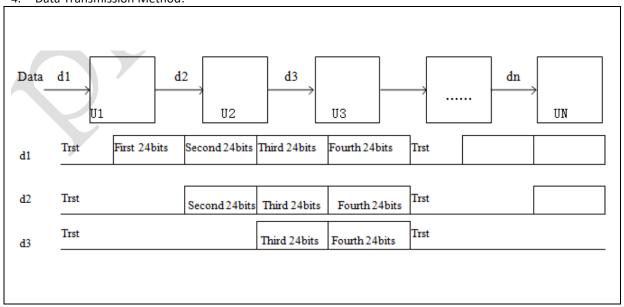
- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye response curve.
- 2. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength λ_D is derived from CIE chromaticity diagram and represents the single wavelength which defines the colour of the device. Peak emission wavelength tolerance is ± 1 nm.

3. Composition of 24 Bit Data:





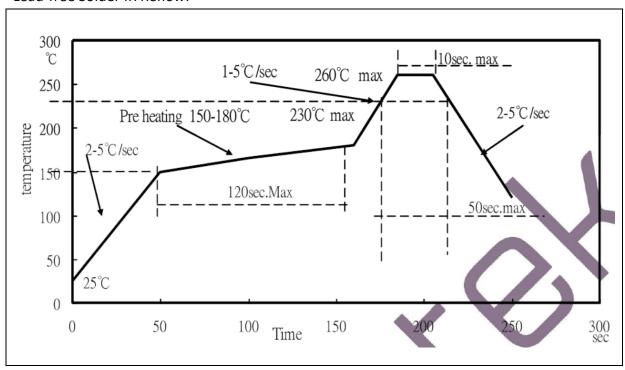
4. Data Transmission Method:





RECOMMENDED SOLDERING PROFILE:

Lead-free Solder IR Reflow:



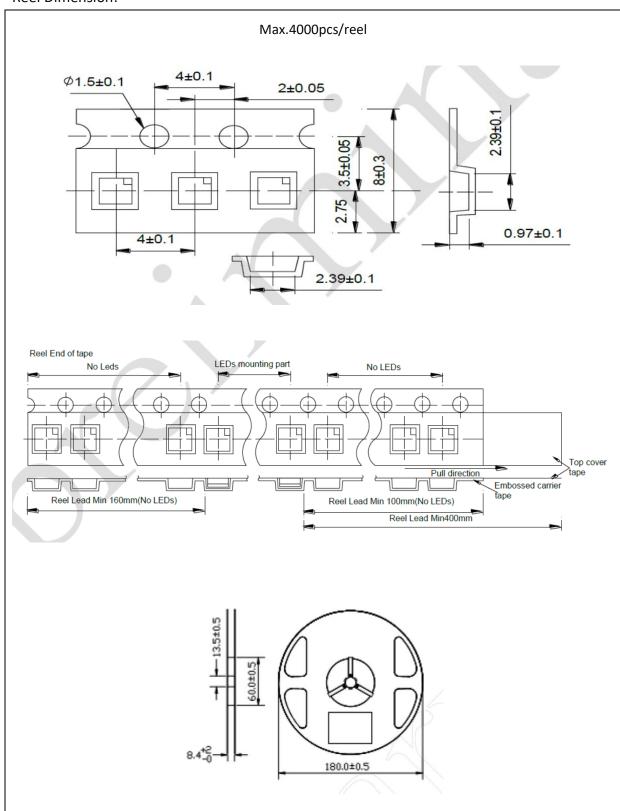
Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 260°C.
- 2. Maxima reflow soldering: 1 time.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



PACKING SPECIFICATION:

Reel Dimension:





PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 24 hours. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<20% and apply baking before use.

Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

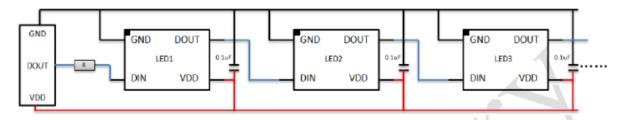
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 6hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



When the first LED is connected to the MCU, a resistance R is needed in series between its signal input line and the MCU. The size of R depends on the number of cascade beads. The more cascade, the smaller resistance R is used. It is generally recommended that the value be between 100-1K. Usually the recommended value is around 300 R. In order to make the LEDs work more stably, a parallel capacitor is needed between VDD and GND of each.

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	22/04/2021	Datasheet set-up.
A1.1	12/09/2024	Add product photos.